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U.S. UTILITY Patent Application						PATENT NUMBER and ISSUE DATE
APPL NUM 10015414	FILING DATE 12/12/2001	CLASS 711	SUBCLASS 185.28	GAU 2485	EXAMINER PHAM	
**APPLICANTS: Fan Tso-Hung; Yeh Yen-Hung; Chan Kwang-Yang; Liu Mu-Yi; Lu Tao-Cheng; 365 2818						
**CONTINUING DATA VERIFIED: no LP						
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** FOREIGN APPLICATIONS VERIFIED: yes <i>HP</i> TAIWAN 90120931 12/04/2001						
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>				
Foreign priority claimed 35 USC 119 conditions met Verified and Acknowledged Examiners's initials <i>LP</i>		<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO JCLA7737		
TITLE : Method for programming and erasing non-volatile memory with nitride tunneling layer U.S. DEPT. OF COM/USPTO-436L (Rev. 12-26-01)						

NOTICE OF ALLOWANCE MAILED		Assistant Examiner		CLAIMS ALLOWED	
				Total Claims	Print Claim for O.G.
ISSUE FEE		Primary Examiner		DRAWING	
Amount Due	Date Paid			Sheets Drawg.	Figs. Drawg.
TERMINAL DISCLAIMER		Application Examiner			
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